



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In application of: **Taiji EMA**

Serial No. 09/050,113

Group Art Unit: 2815

Filed: **March 30, 1998**

Examiner: **M. Warren**

For: **SEMICONDUCTOR DEVICE INCLUDING CONTACT HOLES BETWEEN ADJACENT CONDUCTOR PATTERNS AND METHOD FOR FABRICATING THE SAME (as amended).**

**RESPONSE UNDER 37 C.F.R. §1.116
- EXPEDITED RESPONSE -
GROUP ART UNIT 2815**

RECEIVED
JUN 13 2001
TECHNOLOGY CENTER 2800

BOX AF

Commissioner for Patents
Washington, D. C. 20231

June 13, 2001

Sir:

In response to the Office Action dated February 13, 2001, please amend the above-captioned patent application as follows:

IN THE CLAIMS:

Amend claims 1, 2, 9, 11, 12, 36 and 37 as follows:

1. (Three Times Amended) A semiconductor device comprising:
- a base substrate;
- a first conducting film formed over the base substrate and including two conductor patterns